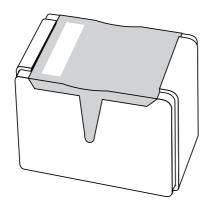
DISCRETE SEMICONDUCTORS

DATA SHEET



BAT254Schottky barrier diode

Product specification Supersedes data of 1999 Apr 22 2002 May 28





Schottky barrier diode

BAT254

FEATURES

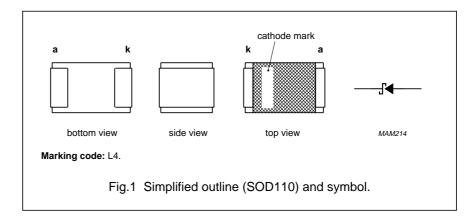
- · Low forward voltage
- · Guard ring protected
- Very small ceramic SMD package.

APPLICATIONS

- Ultra high-speed switching
- Voltage clamping
- · Protection circuits
- Blocking diodes.

DESCRIPTION

Planar Schottky barrier diode encapsulated in a SOD110 very small ceramic SMD package.



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _R	continuous reverse voltage		_	30	V
I _F	continuous forward current		_	200	mA
I _{FRM}	repetitive peak forward current $t_p \le 1$ s; $\delta \le 0.5$ – 3		300	mA	
I _{FSM}	non-repetitive peak forward current	t _p < 10 ms	_	600	mA
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	125	°C
T _{amb}	operating ambient temperature		-65	+125	°C

Schottky barrier diode

BAT254

ELECTRICAL CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT
V _F	forward voltage	see Fig.2		
		I _F = 0.1 mA	240	mV
		$I_F = 1 \text{ mA}$	320	mV
		I _F = 10 mA	400	mV
		I _F = 30 mA	500	mV
		I _F = 100 mA	800	mV
I _R	reverse current	V _R = 25 V; note 1; see Fig.3	2	μΑ
t _{rr}	reverse recovery time	when switched from I_F = 10 mA to I_R = 10 mA; R_L = 100 Ω ; measured at I_R = 1 mA; see Fig.5	5	ns
C _d	diode capacitance	f = 1 MHz; V _R = 1 V; see Fig.4	10	pF

Note

1. Pulse test: $t_p = 300 \ \mu s$; $\delta = 0.02$.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	note 1	315	K/W

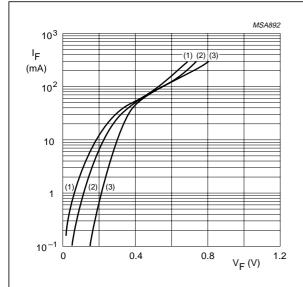
Note

1. Refer to SOD110 standard mounting conditions.

Schottky barrier diode

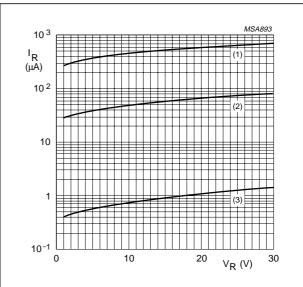
BAT254

GRAPHICAL DATA



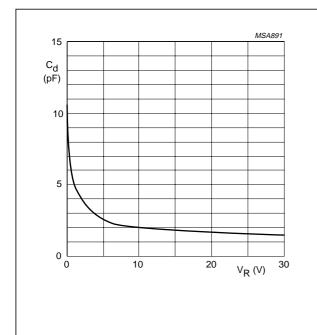
- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \,^{\circ}C$.

Fig.2 Forward current as a function of forward voltage; typical values.



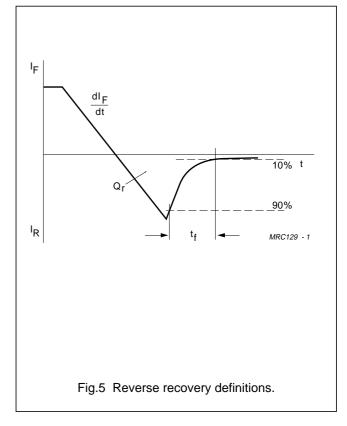
- (1) $T_{amb} = 125 \, ^{\circ}C$. (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \,^{\circ}C$.

Fig.3 Reverse current as a function of reverse voltage; typical values.



f = 1 MHz; $T_{amb} = 25 \, ^{\circ}\text{C}$.

Fig.4 Diode capacitance as a function of reverse voltage; typical values.



2002 May 28

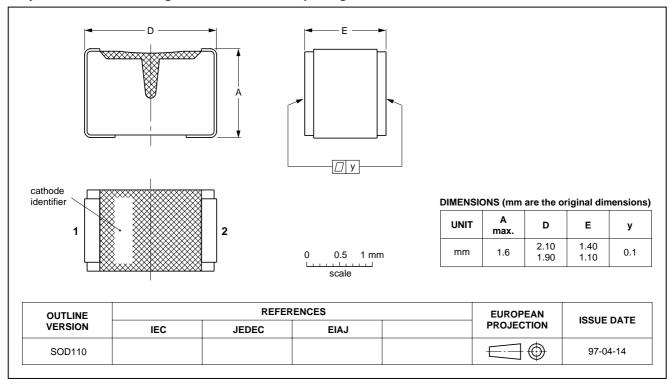
Schottky barrier diode

BAT254

PACKAGE OUTLINE

Very small ceramic rectangular surface mounted package

SOD110



Schottky barrier diode

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DATA SHEET STATUS

DATA SHEET STATUS(1)	PRODUCT STATUS ⁽²⁾	DEFINITIONS
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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Notes

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Schottky barrier diode

BAT254

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SCA74

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